

EN: This Datasheet is presented by the manufacturer.

Please visit our website for pricing and availability at <u>www.hestore.hu</u>.



Low voltage NPN power transistors

Features

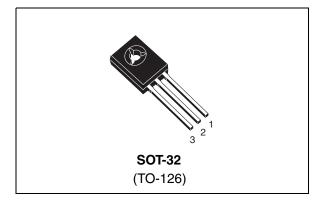
- Low saturation voltage
- NPN transistors

Applications

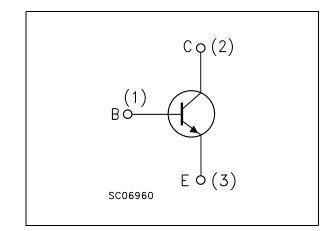
■ Audio, power linear and switching applications

Description

The devices are manufactured in Planar technology with "Base Island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage. The PNP type is BD238.







Order codes	Marking	Package	Packaging	
BD235	BD235	SOT-32	Tube	
BD237	BD237	SOT-32	Tube	

1/9

1 Absolute maximum ratings

Table 2.	Absolute maximum ratings
----------	--------------------------

Symbol	Parameter	Value		Unit
Symbol	Falameter	BD235	BD237	Unit
V _{CBO}	Collector-base voltage ($I_E = 0$)	60	100	V
V _{CER}	Collector-emitter voltage ($R_{BE} = 1 \ k\Omega$)	60	100	V
V _{CEO}	Collector-emitter voltage $(I_B = 0)$	60	80	V
V _{EBO}	Emitter-base voltage ($I_C = 0$) 5		V	
Ι _C	Collector current 2		А	
I _{CM}	Collector peak current (t _p < ms) 6		А	
P _{TOT}	Total dissipation at $T_{case} = 25^{\circ}C$ 25		W	
T _{stg}	Storage temperature -65 to 150		°C	
TJ	Max. operating junction temperature 150		°C	



2 Electrical characteristics

 $(T_{case} = 25^{\circ}C; unless otherwise specified)$

Table 5.						
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
lana	Collector cut-off current	V_{CB} = rated V_{CBO}			0.1	mA
I _{CBO}	(I _E = 0)	V_{CB} = rated $V_{CBO} T_{C}$ = 150°C		-	2	mA
I _{EBO}	Emitter cut-off current $(I_{\rm C} = 0)$	V _{EB} = 5V		-	1	mA
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B = 0)	I _C = 100mA for BD235 for BD237	60 80	-		V V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	I _C = 1A I _B = 0.1A		-	0.6	V
V _{BE(on)} ⁽¹⁾	Base-emitter on voltage	$I_{C} = 1A$ $V_{CE} = 2V$		-	1.3	V
h _{FE} ⁽¹⁾	DC current gain	$I_{C} = 150 \text{mA} \qquad V_{CE} = 2V$ $I_{C} = 1A \qquad V_{CE} = 2V$	40 25	-		

Table 3.Electrical characteristics

1. Pulsed duration = 300 μ s, duty cycle = 1.5 %.

2.1 Electrical characteristic (curves)

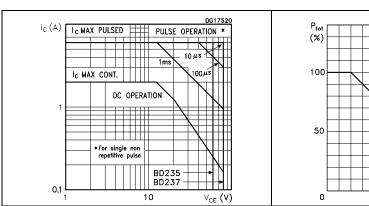
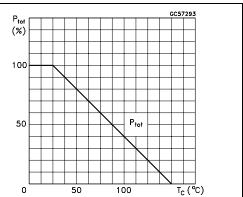


Figure 2. Safe operating area

Figure 3. Derating curves



 $|_{c}(A)$

DG16700

 $I_{C}(A)$

DC current gain (V_{CE} = 2 V) Figure 5. DC current gain ($V_{CE} = 4 V$) Figure 4.

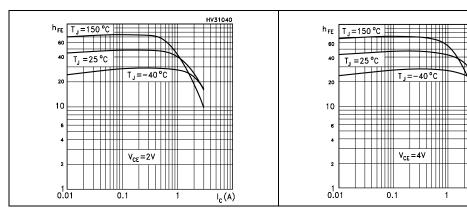


Figure 6. **Collector-emitter saturation**

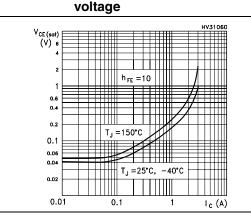


Figure 7. **Base-emitter saturation** voltage

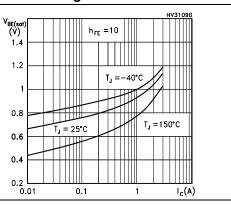
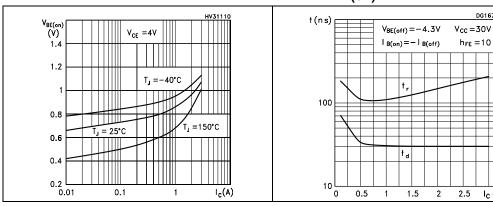


Figure 8. **Base-emitter on voltage**

Figure 9. **Resistive load switching time** (on)



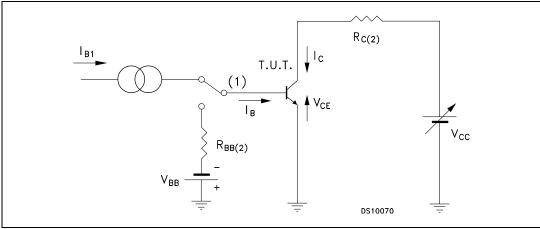


	(01)					
t (n s)		V _{BE(of}	f)=-4	.3V		DG16710 30V	
	\searrow	B(on))=- в(off)		=10	
1000				\searrow	† _s		
100	\searrow	t,		_			
-							
10	0.5	1	1.5	2	2.5	I _C (A)	

Figure 10. Resistive load switching time (off)

2.2 Test circuit

Figure 11. Resistive load switching test circuit



1. Fast electronic switch

2. Non-inductive resistor



3 Package mechanical data

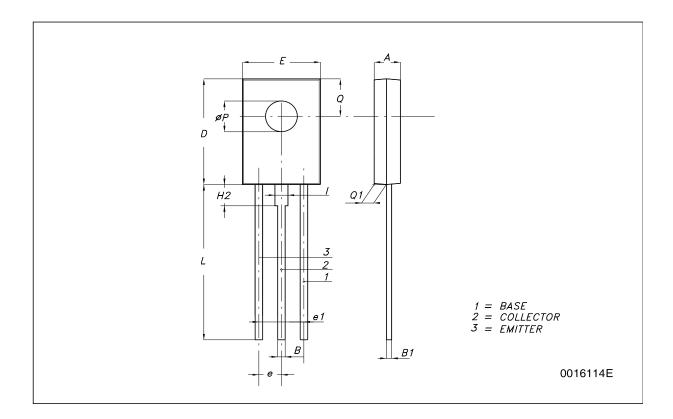
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.



57

SOT-32 (TO-126) MECHANICAL DATA

DIM		mm.			
DIM.	MIN.	ТҮР	MAX.		
А	2.4		2.9		
В	0.64		0.88		
B1	0.39		0.63		
D	10.5		11.05		
Е	7.4		7.8		
е	2.04	2.29	2.54		
e1	4.07	4.58	5.08		
L	15.3		16		
Р	2.9		3.2		
Q		3.8			
Q1	1		1.52		
H2		2.15			
I		1.27			





57

4 Revision history

Table 4. Document	revision	history
-------------------	----------	---------

Date	Revision	Changes
11-Feb-2003	1	Initial release.
09-Jul-2007	2	Added: figures 2, 3, 4, 5, 6, 7, 8, 9, 10, 11 and 12.
03-Jun-2009	3	Minor text changes.



Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2009 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

